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			U.S. PATENT DOCUMENT	'S	·
Examiner Initials	Cited No.	U.S. Patent Document	Name of Patentee or Applicant of Cited	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number Kind Code ² (If known)	Document		
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OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS					
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Examiner Signature	23-1/	14-	Date Considered 1/18/04

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